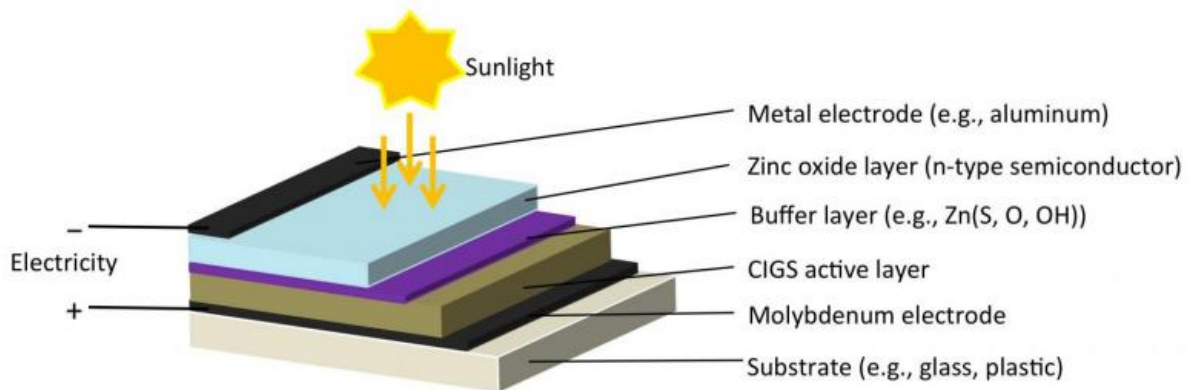


Finding a way to boost efficiency of CIGS solar cells

September 28 2015



The configuration of a typical CIGS solar cell. Credit: Copyright (C) 2015 Toyohashi University Of Technology

CIGS (copper-indium-gallium-selenide) solar cells are compound thin-film solar cells and the most established alternative to silicon solar cells. Solar conversion efficiencies of over 20% have recently been achieved in CIGS solar cells.

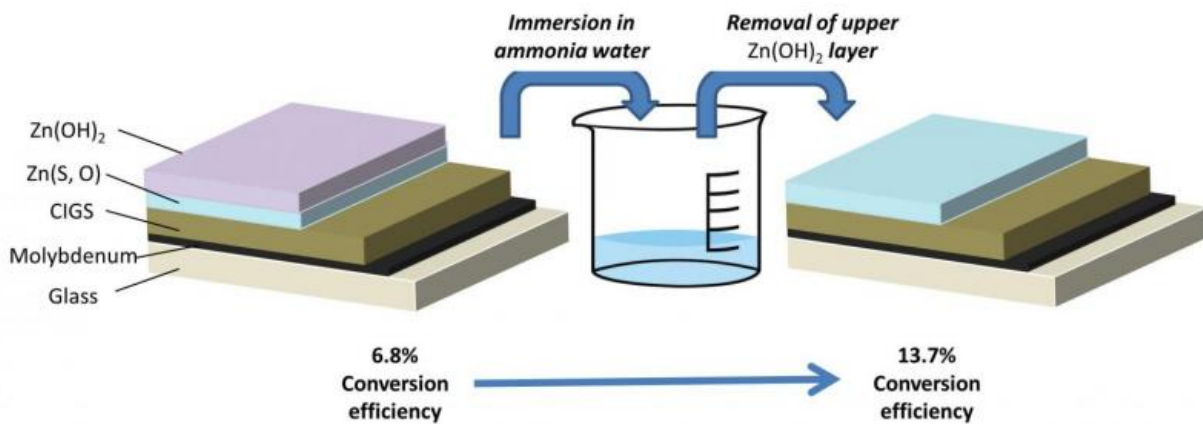
One of the factors known to strongly affect the [conversion efficiency](#) is the buffer layer (see Figure 1). However, the structure of the buffer layer and its precise influence on the conversion efficiency have not been clarified. Professor Masanobu Izaki and colleagues at Toyohashi

University of Technology, in collaboration with researchers at the Research Center for Photovoltaic Technologies, National Institute of Advanced Industrial Science and Technology, have analyzed the structure of a zinc-based buffer layer in a CIGS solar cell at SPring8 (the world's largest third-generation synchrotron radiation facility, located in Hyogo Prefecture, Japan).

"Performing structural analysis on very thin films is extremely difficult," Professor Izaki said.

The researchers revealed the structure of the buffer layer and identified a way to improve the conversion efficiency. The study was published online in *Progress in Photovoltaics* on August 17, 2015.

"We analyzed the structure of the buffer layer by X-ray photoelectron spectroscopy, transmission electron microscopy, and other techniques. We found that the buffer layer was composed of two layers: an upper Zn(OH)₂ layer and a lower Zn(S, O) layer. Moreover, the conversion efficiency was improved from 6.8% to 13.7% by removing the upper Zn(OH)₂ layer," Professor Izaki said.



The deposited Zn(S, O, OH) buffer layer was found to consist of sublayers of Zn(S, O) and Zn(OH)₂. Immersion in aqueous ammonia removed the topmost layer (Zn(OH)₂), which resulted in a doubling of the solar conversion efficiency. Credit: Copyright (C) 2015 Toyohashi University Of Technology.

In their article, the researchers described how to remove the upper Zn(OH)₂ layer. The method is simple but impressive: quick immersion of a 120-nm-thick film in ammonia led to a doubling of the solar conversion efficiency (see Figure 2).

This study reveals the importance of the [buffer layer structure](#) and composition, and is expected to be a valuable step for the development of next-generation CIGS [solar cells](#). It is anticipated that once CIGS cells are able to be mass produced at reduced cost, they will become a main player in the solar cell market.

More information: Masanobu Izaki, Shinya Sugiyama, Tetsuhito Okamoto, Yuya Kusano, Takeshi Maki, Hironori Komaki, Hajime Shibata, and Shigeru Niki (2015). Structure of Chemically Deposited Zn(S, O, OH) Buffer Layer and the Effects on the Performance of Cu(In, Ga)Se₂ Solar Cell, *Progress in Photovoltaics*, Article first published online: 17 AUG 2015 | [DOI: 10.1002/ppp.2666](https://doi.org/10.1002/ppp.2666)

Provided by Toyohashi University of Technology

Citation: Finding a way to boost efficiency of CIGS solar cells (2015, September 28) retrieved 24 April 2024 from <https://phys.org/news/2015-09-boost-efficiency-cigs-solar-cells.html>

This document is subject to copyright. Apart from any fair dealing for the purpose of private

study or research, no part may be reproduced without the written permission. The content is provided for information purposes only.